



Broadband opto-electrical receivers in standard CMOS /

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Monografía

"This book fits in the quest for integrated opto-electrical solutions, and focuses on the receiver front-end. To further reduce the cost, the cheapest technology is selected: standard CMOS, without any optical tricks or flavors. The emphasis lies on the analysis design and implementation of high performance analog receiver circuits."--Jacket

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Contenido: Machine derived contents note: 1 1 A History of Optical Communication -- 1.2 Emerging Applications 4 -- 1.3 Silicon Opto-Electronics 7 -- 1.4 Outline of the Work 9 -- 2 Optical Receiver Fundamentals 13 -- 21 Introduction 13 -- 2.2 The Optical Receiver Front-End 13 -- 2.2.1 A Transceiver for Optical Communication Systems 13 -- 2.2.2 A Pickup Unit for Optical Storage Systems 15 -- 2.3 Binary Data Formats 17 -- 2.4 Bit Error Rate and Sensitivity 20 -- 2.4.1 Bit Error Rate 20 -- 2.4.2 Sensitivity 22 -- 2.5 Intersymbol Interference. 23 -- 2.5.1 Low-Pass Filtering 23 -- 2.5.2 High-Pass Filtering 24 -- 2.6 Jitter 25 -- 2.7 Conclusions 26 -- 3 Standard CMOS Photodiodes 27 -- 3.1 Introduction 27 -- 3.2 Basic Concepts 27 -- 3.2.1 Principles of Light Detection, 28 -- 3.2.2 The Use of Standard CMOS 31 -- 3.3 Overview of Published Integrated Photodiodes 32 -- 3.3.1 BiCMOS Implementations 32 -- 3.3.2 SOI Implementations 34 -- 3.3.3 CMOS Implementations. 35 -- 3.3.4 Conclusions 36 -- 3.4 One-Dimensional Model 37 -- 3.4.1 N-Well P-Substrate Junction 37 -- 3.4.2 P⁺ N-Well Junction with Guard 43 -- 3.5 Two-Dimensional Model 46 -- 3.5.1 Classical N-Well Diode 46 -- 3.5.2 P⁺ N-Well Diode with Guard 49 -- 3.5.3 Differential N-Well Diode. 51 -- 3.5.4 Influence of Wavelength 52 -- 3.5.5 Influence of Technology Scaling 56 -- 3.6 Conclusions 58 -- 4 Transimpedance Amplifier Design 61 -- 4.1 Introduction 61 -- 4.2 Performance Requirements 61 -- 4.3 Design of the Shunt-Shunt Feedback TIA 63 -- 4.3.1 Transimpedance Gain and Bandwidth 64 -- 4.3.2 Open-Loop Gain and Loop Gain 68 -- 4.3.3 Noise 70 -- 4.4 Literature Examples 76 -- 4.4.1 Common Source TIA 77 -- 4.4.2 Regulated Cascode TIA 78 -- 4.4.3 The Latest Trends at ISSCC 80 -- 4.5 Case Studies 81 --

4.5.1 An Inverter-Based TIA for Test Photodiodes -- in 0.18 nm CMOS 82 -- 4 5.2 An Inverter- Based TIA for Test Photodiodes -- in 90 nm CMOS 93 -- 4.5.3 A Differential Bandwidth-Optimized TIA in 0 18 um -- C M O S 97 -- 4.6 C onclusions 103 -- 5 Post-Amplifier Design 107 -- 5.1 Introduction 107 -- 5.2 Performance Requirements 108 -- 5.3 Literature Examples 110 -- 5.4 Design of a Fully Differential Broadband LA 113 -- 5.4.1 Cascaded Gain Stages 114 -- 5.4.2 Broadband Cherry-Hooper Stage 116 -- 5.4.3 Broadband Stage with Capacitive Source Degeneration. 120 -- 5.4 Offset Compensation. 122 -- 5.5 Case Studies, 124 -- 5.5.1 A Four-Stage LA in 0.18 p.m CMOS 124 -- 5.5,2 A Five-Stage LA with Offset Compensation -- in 0.18 pim CMOS 126 -- 5,6 C onclusions 129 -- SCMOS Realizations 133 -- 6.1 Introduction 133 -- 6.2 Test Photodiodes with TIA in 0.18 im CMOS 135 -- 6.2.1 Circuit Description 135 -- 6.2.2 Measurements 138 -- 6.3 Test Photodiodes with TIA in 90 nm CMOS 142 -- 6.3.1 Circuit Description 143 -- 6.3 2 Measurements 144 -- 6.4 A 3.5 Gbit/s LA in 0.18 gm CMOS 146 -- 6.4.1 Circuit Description 147 -- 6.4.2 Measurements 149 -- 6.5 A Gbit/s Monolithic Optical Receiver Front-End -- in 0.18 unnm CMOS 152 -- 6.5.1 Circuit Description 152 -- 6.5.2 Measurements 157 -- 6.6 Conclusions 164

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